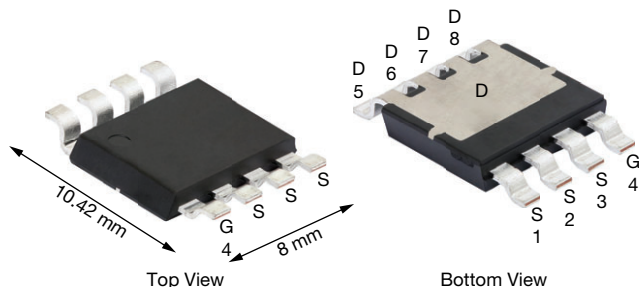
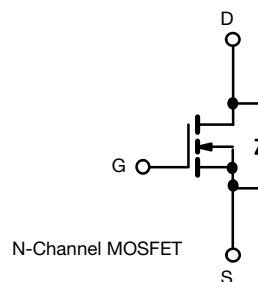


Automotive N-Channel 150 V (D-S) 175 °C MOSFET

PowerPAK® 8 x 8LR


FEATURES

- TrenchFET® Gen V power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Thin 1.9 mm height
- Material categorization:
for definitions of compliance please see
www.vishay.com/doc?99912


RoHS
COMPLIANT
HALOGEN
FREE


PRODUCT SUMMARY	
V_{DS} (V)	150
$R_{DS(on)}$ (Ω) at $V_{GS} = 10$ V	0.0041
I_D (A) ^e	189
Configuration	Single

ORDERING INFORMATION	
Package	PowerPAK 8 x 8LR
Lead (Pb)-free and halogen-free	SQJQ570ER (for detailed order number please see www.vishay.com/doc?79776)

ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	150	V
Gate-source voltage		V_{GS}	± 20	
Continuous drain current ^e	$T_C = 25$ °C	I_D	189	A
	$T_C = 125$ °C		109	
Continuous source current (diode conduction) ^e		I_S	340	
Pulsed drain current ^{a, e}		I_{DM}	576	
Single pulse avalanche current		I_{AS}	55	
Single pulse avalanche energy		E_{AS}	154	mJ
Maximum power dissipation ^{c, e}	$T_C = 25$ °C	P_D	375	W
	$T_C = 125$ °C		125	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +175	°C
Soldering recommendations (peak temperature) ^c			260	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^b	R_{thJA}	40	°C/W
Junction-to-case (drain lead) ^d		R_{thJL}	0.7	
Junction-to-case (pad) ^d as measured at drain pad		R_{thJC}	0.4	

Notes

- Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %
- When mounted on 1" square PCB (FR4 material)
- See solder profile (www.vishay.com/doc?73257). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- As per JESD51-14
- Values based on R_{thJC} and T_C of 25 °C. Actual values achievable will be dependent on the thermal characteristics of the complete system



SPECIFICATIONS (T _C = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0, I _D = 250 μA		150	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA		2.4	3	3.6	
Gate-source leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V		-	-	± 100	nA
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 150 V	-	-	10	μA
		V _{GS} = 0 V	V _{DS} = 150 V, T _J = 125 °C	-	-	50	
		V _{GS} = 0 V	V _{DS} = 150 V, T _J = 175 °C	-	-	500	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	V _{DS} ≥ 5 V	50	-	-	A
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 20 A	-	0.0034	0.0041	Ω
		V _{GS} = 10 V	I _D = 20 A, T _J = 125 °C	-	-	0.0081	
		V _{GS} = 10 V	I _D = 20 A, T _J = 175 °C	-	-	0.0105	
Forward transconductance ^b	g _{fs}	V _{DS} = 15 V, I _D = 40 A		-	150	-	S
Dynamic ^b							
Input capacitance	C _{iss}	V _{GS} = 0 V	V _{DS} = 25 V, f = 1 MHz	-	7326	10 257	pF
Output capacitance	C _{oss}			-	2857	4000	
Reverse transfer capacitance	C _{rss}			-	610	854	
Total gate charge ^c	Q _g	V _{GS} = 10 V	V _{DS} = 75 V, I _D = 50 A	-	85	128	nC
Gate-source charge ^c	Q _{gs}			-	39	-	
Gate-drain charge ^c	Q _{gd}			-	4	-	
Gate resistance	R _g	f = 1 MHz		0.9	1.8	2.7	Ω
Turn-on delay time ^c	t _{d(on)}	V _{DD} = 75 V, R _L = 1.5 Ω, I _D ≅ 50 A, V _{GEN} = 10 V, R _g = 1 Ω		-	19	29	ns
Rise time ^c	t _r			-	70	105	
Turn-off delay time ^c	t _{d(off)}			-	40	60	
Fall time ^c	t _f			-	12	18	
Source-Drain Diode Ratings and Characteristics ^b							
Pulsed current ^a	I _{SM}			-	-	576	A
Forward voltage	V _{SD}	I _F = 40 A, V _{GS} = 0 V		-	0.7	1.1	V
Body diode reverse recovery time	t _{rr}	I _F = 40 A, di/dt = 100 A/μs		-	101	202	ns
Body diode reverse recovery charge	Q _{rr}			-	387	774	nC
Reverse recovery fall time	t _a			-	75	-	ns
Reverse recovery rise time	t _b			-	27	-	
Body diode peak reverse recovery current	I _{RM(REC)}			-	7.1	-	A

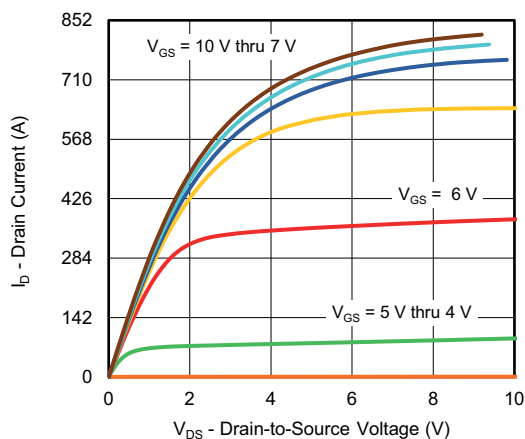
Notes

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
b. Guaranteed by design, not subject to production testing
c. Independent of operating temperature

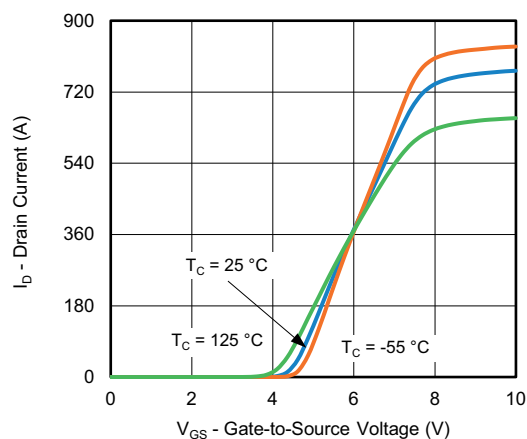
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



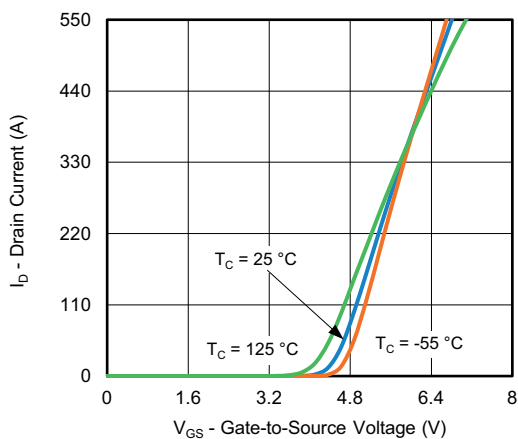
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



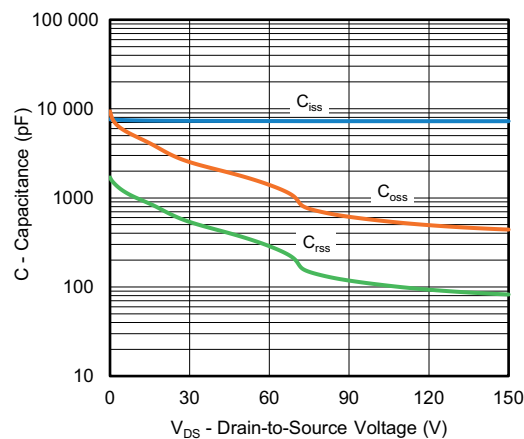
Output Characteristics



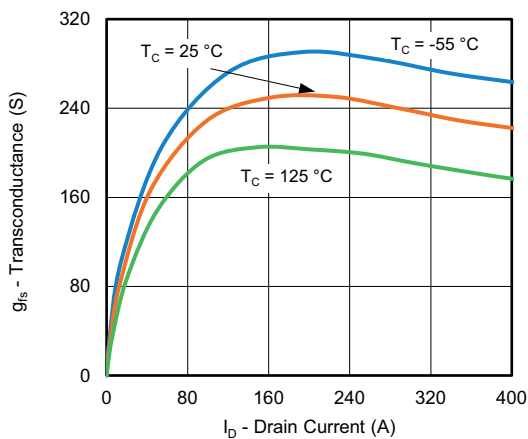
Transfer Characteristics



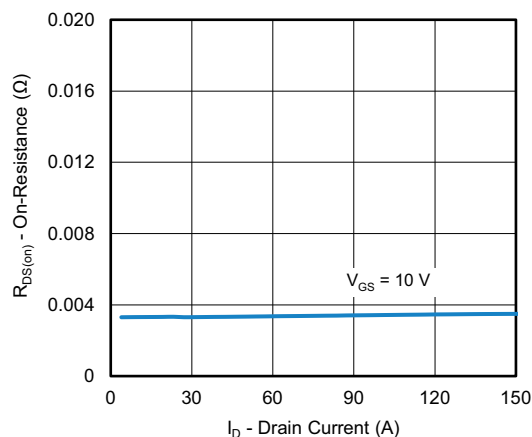
Transfer Characteristics



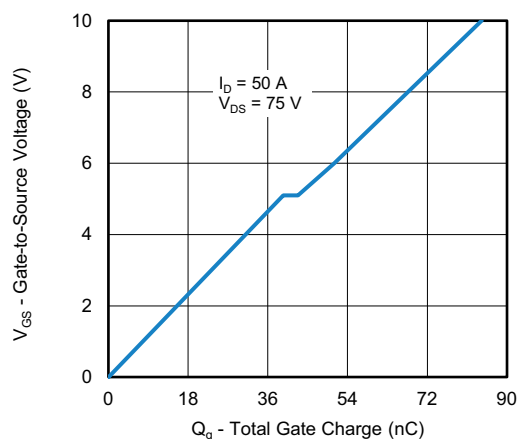
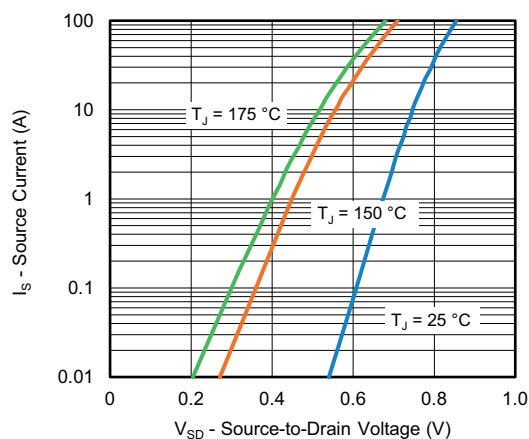
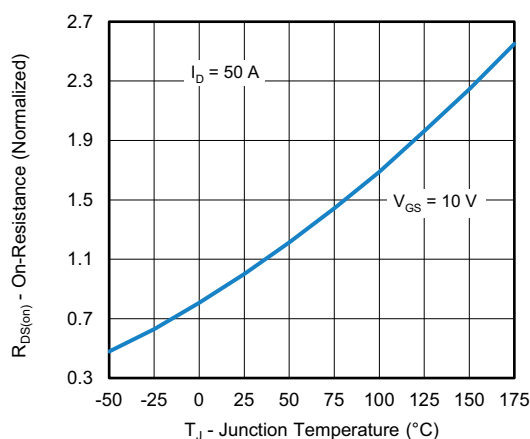
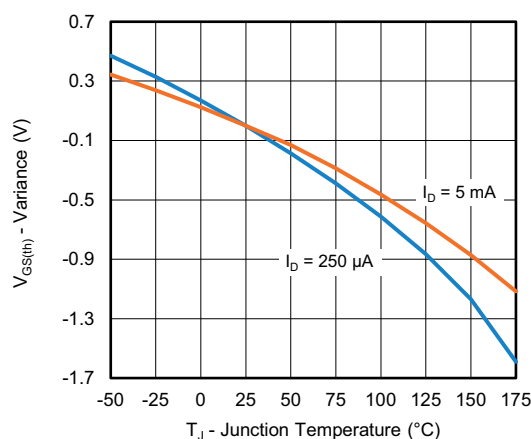
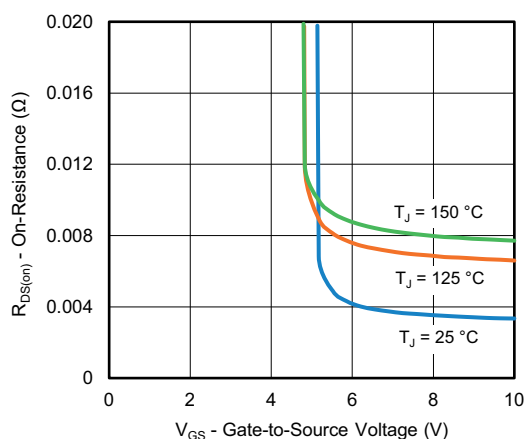
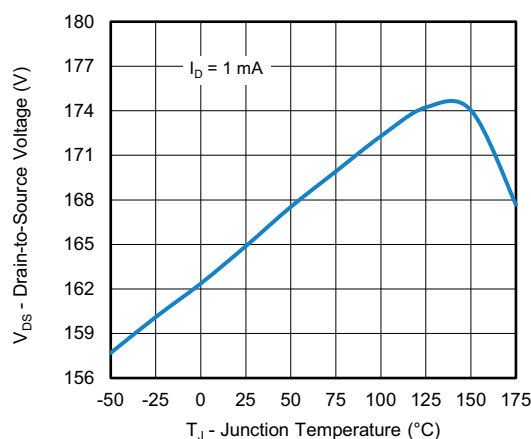
Capacitance



Transconductance

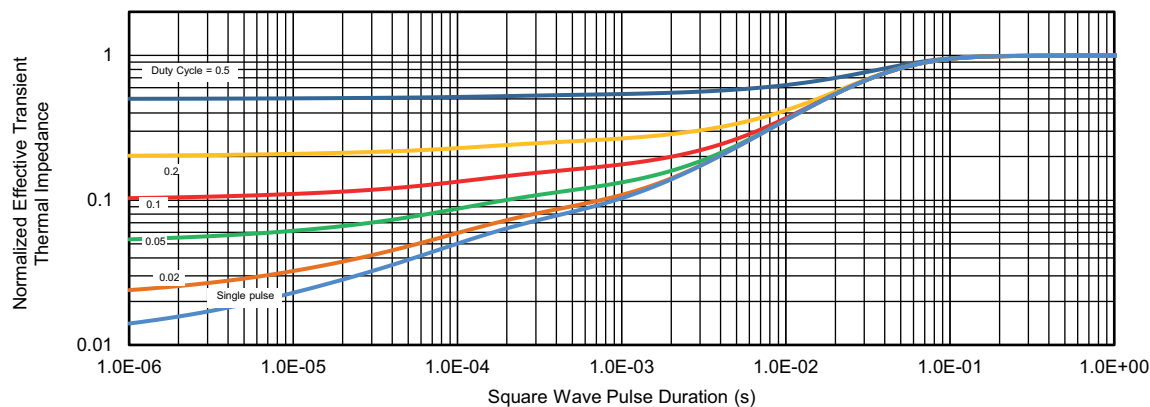


On-Resistance vs. Drain Current

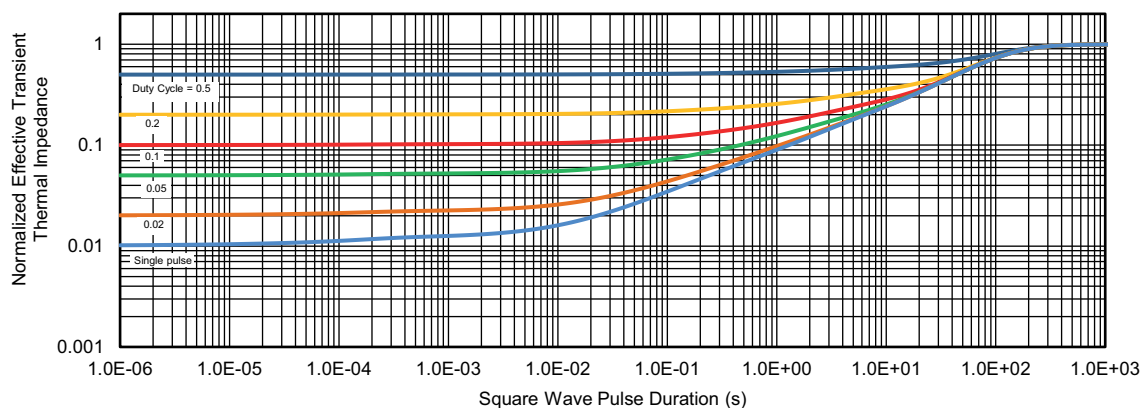
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)

Gate Charge

Source Drain Diode Forward Voltage

On-Resistance vs. Junction Temperature

Threshold Voltage

On-Resistance vs. Gate-to-Source Voltage

Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient

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